arXiv:cond-mat/0508571v1 [cond-mat.dis-nn] 24 Aug 2005

A new approach to strongly correlated disorder

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Abstract

Problems involving disordered systems are usually analyzed for systems with random disorder. However, there are many systems in which the main disorder involves clusters with correlated differences between their properties and those of the average system. A new approximation, the average trace approximation, is proposed for calculating the diagonal elements of the Green function, and hence the density of states, in such systems. As an example, application of the method to a simple cubic array of harmonic oscillators shows that correlation in the disorder leads to a peak in the low frequency density of states, a result confirmed by computer simulations.

There are many problems in the physics of condensed matter that involve the behavior of disordered systems. The simplest type of disorder involves fluctuations in the diagonal elements of the system's Hamiltonian. For electronic systems, such problems correspond to fluctuations in the electron's self energy, while for vibrational problems it corresponds to isotopic impurities, i.e. fluctuations in the masses of the atoms. The most powerful method to study the effect of such disorder is the coherent potential approximation (CPA).[1] Another type of disordered system that has been widely studied is that of off-diagonal disorder in the elements of the Hamiltonian between adjacent sites. Examples of this for electrons include random hopping rates between different sites[2] and the migration of localized electronic excitations among guest molecules in a host.[3] The corresponding problem for vibrations is that of bond disorder, which is modelled by systems of harmonic oscillators with random distributions of spring constants[4] All these authors use a coherent medium approximation (CMA) that is essentially equivalent to the CPA. Spin glasses are an example of a more complicated random system, which we will not consider in this paper, since they are not usually treated in terms of Green functions.

In all the above system, it is usually assumed that the disorder is random. Even when correlated disorder is considered, it is often treated in terms of a probability distribution of the correlation decaying with distance between the sites.[5] This is not the type of correlation that is relevant to specific defect clusters involving several sites or bonds with correlated properties different from those of the surrounding medium. Such defects can easily occur, for instance with the bonds to atoms with irregular coordination numbers and the electronic states associated with them. Other examples include clusters of molecules in liquids, and atoms or electronic states in the region of grain boundaries in crystals or in regions of increased or decreased density in glasses and fluids. For electronic systems, the homomorphic coherent cluster approximation (HCPA)[6] was proposed (which actually was the original basis for the CMA) to treat such problems, and had some success. However, there are grave practical difficulties in using it in more than one dimension for clusters containing more than two sites, since it is difficult to find clusters of identical shape (homomorphic) that span the whole system and for which calculations are practicable. For instance, the smallest such cluster for a simple cubic lattice contains seven sites, the central one and its six nearest neighbors. In addition, a fundamental objection has been raised to the use of the HCPA,[7] namely that the sites on the edge of the cluster are regarded partly as belonging to the cluster and partly to the average surrounding medium, so that it is far from clear when use of the HCPA is justified. In this paper, we present a new method for calculating the density of states in systems containing a low density of clusters with correlated disorder, which is based on the T-matrix formalism for the calculation of Green functions and a new approximation to the diagonal elements of the Green function which we call the average trace approximation (AVTA). As an example of the application of this method, we consider its application to a simple cubic array of harmonic oscillators containing defects for which all the spring constants are weak. For

this system, we find a low frequency peak in the density of states which is not present for the same amount of random disorder, and our results (and hence the accuracy and usefulness of the AVTA) are confirmed by computer simulations.

The systems that we consider have a Hamiltonian of the form

$$H = H_0 + H_p \tag{1}$$

where H_0 is a Hamiltonian having a known Green function G_0 and the perturbation (not necessarily small) H_p can be expressed in the appropriate basis set as the sum of Hamiltonians $H_\alpha, \quad \alpha = 1...M$ associated with M disjoint clusters For convenience, we will consider the most common case, in which H_0 is the Hamiltonian of a crystal and we use the site representation, in which we denote a site by $\mathbf{n}$, so that an operator F can be written as $\sum_{\mathbf{m}} \sum_{\mathbf{n}} |\mathbf{m} > F < \mathbf{n}|$. Our aim is to calculate the density of states $g(E)$ in the system from the trace of its Green function,[8]

$$g(E) = \mp \frac{1}{\pi} \operatorname{Im}\{Tr[G(E \pm i\epsilon)]\}. \tag{2}$$

For the calculation of G, we use the T-matrix formalism, and write

$$G(z) = G_0(z) + G_0(z)T(z)G_0(z), \tag{3}$$

where

$$T(z) = H_p[I - G_0(z)H_p]^{-1}. \tag{4}$$

For random disorder, the above formalism is usually used either in the average T-matrix approximation (ATA), where one writes $< G(z) >= G_0(z) + G_0(z) < T(z) > G_0(z)$, or in the CPA, in which one finds the value of z for which $< T(z) >= 0$. However, even the extension of the ATA to clusters of more than two sites involves all the above-mentioned problems of the HCPA. In addition, even for two sites there are problems in defining the operator P required to solve equation (7), as described below after equation (12). In this paper, we propose an entirely different method for calculating the diagonal elements of G, and hence the density of states.

While a general operator F has non-zero matrix elements between any pair of sites, the Hamiltonian H_p of the perturbation is the sum of Hamiltonians H_α each of which is associated with a cluster containing only a few sites. In that case, if a cluster centred around $\mathbf{n}_\alpha$ contains only the site $\mathbf{n}_\alpha$ and some adjacent sites $\mathbf{n}_\alpha + \mathbf{a}_k, \quad k = 1..R$, it is convenient to introduce the row vector $|\alpha >= (|\mathbf{n}_\alpha >, |\mathbf{n}_\alpha + \mathbf{a}_1 >, ..., |\mathbf{n}_\alpha + \mathbf{a}_R >)$, as proposed by Economou[8] In order to present our method, we consider first the conventional case where each cluster consists of only a single site, so that two clusters $\alpha = 1, 2$ contain only $|\mathbf{n}_1 >$ and $|\mathbf{n}_2 >$ respectively, and write $G(z; \mathbf{n}_1, \mathbf{n}_2) = < \mathbf{n}_1|G(z)|\mathbf{n}_2 >$, and similarly $T(z; \mathbf{n}_1, \mathbf{n}_2) = < \mathbf{n}_1|T(z)|\mathbf{n}_2 >$. In this notation, we can write

$$H_1 = \sum_{\alpha=1}^{M} H_\alpha = \sum_{\alpha=1}^{M} |\mathbf{n}_\alpha > V_\alpha < \mathbf{n}_\alpha|. \tag{5}$$

where V_α is the matrix (in this case a scalar) describing the perturbation at site $\mathbf{n}_\alpha$. For a system containing only a single defect at site $\mathbf{n}_\alpha$, it readily follows from equations (4) and (5) that the corresponding operator T_α is just $T_\alpha = |\mathbf{n}_\alpha > t_\alpha < \mathbf{n}_\alpha|$, where t_α is a scalar,

$$t_\alpha = V_\alpha[1 - < \mathbf{n}_\alpha|G_0|\mathbf{n}_\alpha > \mathbf{V}_\alpha]^{-1}. \tag{6}$$

If there are a number of defects, one can write

$$T = \sum_\alpha Q_\alpha = \sum_\alpha [T_\alpha + T_\alpha G_0 \sum_{\beta \neq \alpha} Q_\beta], \tag{7}$$

where Q_α is the contribution to the scattering matrix T from the defect at $\mathbf{n}_\alpha$ in the presence of all the other defects. Iteration of this equation leads to the standard equation

$$Q_\alpha = \sum_{\beta \neq \alpha} \sum_{\gamma \neq \beta} \cdot\cdot T_\alpha + T_\alpha G_0 T_\beta + T_\alpha G_0 T_\beta G_0 T_\gamma + ... \tag{8}$$

These equations can be generalized to defects containing more than one site by replacing the scalars $|\mathbf{n}_\alpha >$ with the vectors $|\alpha >$ throughout, in which case V_α, $G_\alpha =< \alpha|G_0|\alpha >$ and t_α will be square matrices. In order to show this, we consider a specific cluster α, and write $\mathbf{m}_k = \mathbf{n}_\alpha + \mathbf{a}_k$. Then, for instance

$$H_\alpha = |\alpha > V_\alpha < \alpha| = \sum_{k,l} |\mathbf{m}_k > V_{kl} < \mathbf{m}_l|, \tag{9}$$

and since $< \mathbf{r}|\mathbf{s} >= \delta_{\mathbf{r},\mathbf{s}}$ it follows that $< \mathbf{r}|H_\alpha|\mathbf{s} >= \delta_{\mathbf{r},\mathbf{m}_k}\delta_{\mathbf{s},\mathbf{m}_l}V_{kl}$, and so that $V_{kl} =< \mathbf{m}_k|H_\alpha|\mathbf{m}_l >$ is the element (k,l) of the matrix $V_\alpha =< \alpha|H_\alpha|\alpha >$. Similar definitions apply to the matrices $G_\alpha =< \alpha|G_0|\alpha >$ and t_α, and it can easily be shown that the equivalent of equation (6) for our matrices is

$$t_\alpha = V_\alpha[I - G_\alpha \mathbf{V}_\alpha]^{-1} \tag{10}$$

Thus, in general we can write

$$T = \sum_\alpha \sum_{\beta \neq \alpha} \sum_{\gamma \neq \beta} \cdot\cdot T_\alpha + T_\alpha G_0 T_\beta + T_\alpha G_0 T_\beta G_0 T_\gamma + ..., \tag{11}$$

where now

$$T_\alpha = |\alpha > t_\alpha < \alpha| = \sum_{k,l} t_{kl} |\mathbf{m}_k >< \mathbf{m}_l|. \tag{12}$$

However, while for single site clusters equation (7) can be solved by defining an operator $P = G_0 - < \mathbf{n}_\alpha|G_0|\mathbf{n}_\alpha >$, this method does not apply to solving equation (11) for clusters containing more than one site. Instead, we note that for the density of states we only need the trace of G and so of G_0 and of $G_0 T G_0$. In order to calculate the latter, we introduce the average trace approximation (AVTA), in which we write

$$\langle Tr\{G_0 T G_0\}\rangle \approx \langle Tr\{G_0(\sum_{\alpha=1}^{M} T_\alpha)G_0\}\rangle = M\langle Tr\{G_0|\alpha > t_\alpha < \alpha|G_0\}\rangle, \tag{13}$$

where $\langle . \rangle$ denotes the mean value and M is the number of defect clusters. In the AVTA it is essential to take the trace before averaging, since (in contrast to the ATA and CPA) we do not average out the defects over the whole system and calculate $\langle G \rangle$ for the periodic average system. The justification of the AVTA for small defect densities is that the first term which we are ignoring in $Tr\{G_0 T G_0\}$ is $Tr\{G_0 T_\alpha G_0 T_\beta G_0\}$ where $\beta \neq \alpha$. On taking the trace in the site representation, we write

$$Tr\{G_0 T_\alpha G_0 T_\beta G_0\} = \sum_{\mathbf{n}} < \mathbf{n}|G_0|\alpha > t_\alpha < \alpha|G_0|\beta > t_\beta < \beta|G_o|\mathbf{n} > .$$

Each term of this sum involves the matrix elements of G_0 between sites belonging to two different defects multiplied by the matrix elements of G_0 between a site $\mathbf{n}$ and one site from each defect. These terms will be small if the defects are far apart, as they will be for low defect densities. In terms of Feynman diagrams, the first terms that we are ignoring correspond to propagation from an arbitrary site to one defect, from that to the second defect, and then back to the original site. If we were interested in non-diagonal elements of G, for some of which a path starts at a site close to cluster α and ends at a site close to cluster β, this approximation would not be justified.

For the calculation of $Tr\{G_0|T_\alpha|G_0\}$ for a given cluster α, we write $G_0(z)$ in the form $G_0(z) = \sum_{\mathbf{k}} |\mathbf{k}><\mathbf{k}|/(z - E_{\mathbf{k}})$ and use equation (12) for T_α, while $< \mathbf{k}|\mathbf{n} >= \exp(-i\mathbf{k} \cdot \mathbf{n})$. It then follows that

$$Tr\{G_0(z)|T_\alpha(z)|G_0(z)\} = \frac{M}{N} \sum_{l,m} \sum_{\mathbf{k}} t_{lm} \frac{\exp[i\mathbf{k} \cdot (\mathbf{a}_m - \mathbf{a}_l)]}{(z - E_{\mathbf{k}})^2}, \qquad (14)$$

which depends only on the distances $\mathbf{a}_m - \mathbf{a}_l$ between pairs of sites in a cluster. In order to evaluate the trace in terms of the known expressions for $G_0(z; \mathbf{a}_l, \mathbf{a}_m)$, we write equation (14) in the form

$$Tr\{G_0(z)|T_\alpha(z)|G_0(z)\} = -M \frac{\partial}{\partial z} \sum_{l,m} t_{lm} G_0(z; \mathbf{a}_l, \mathbf{a}_m). \qquad (15)$$

In order to demonstrate the usefulness and accuracy of the AVTA, we now apply it to a specific system, and compare its results with those of computer simulations. The model system that we consider is a simple cubic lattice of coupled harmonic oscillators with spring constants K. For the sake of simplicity we chose a binary distribution, with a small fraction of oscillators having a spring constant K_1 (which we refer to as weak springs) much less than the spring constant K_0 of most of the oscillators. Extensive results for a random distribution of weak springs in this system have been presented by Schirmacher and Diezemann.,[9] who found that a concentration of 10% of weak springs had a negligible effect on the density of vibrational states. In contrast to their model, we considered systems in which the weak springs occur in clusters, with the same type of cluster in each defect. The defects that we consider are those in which

a site is linked to its six neighbors by weak springs, with $K_1/K_0 = 0.1$. The results for more general systems of this type, in which a site is linked to its six neighbors by z weak springs with spring constant K_1 and $6-z$ ordinary springs with spring constant K_0, as well as the results for other values of K_1/K_0, will be reported elsewhere The concentration $c = M/N$ of these defects was chosen to be 1.5%, so that the total concentration of weak springs was 9%. Since the clusters are identical, it follows from equation (15) that they each give the same contribution to $Tr\{G_0 T_\alpha G_0\}$. Thus it is sufficient to calculate $Tr\{G_0 T_\alpha G_0\}$ for one such cluster, so that

$$Tr\{G\} = Tr\{G_0\} + cNTr\{G_0 T_\alpha G_0\}, \tag{16}$$

and for the density of states per site

$$\frac{1}{N}Tr\{G\} = G_0(z;\mathbf{0},\mathbf{0}) - c\frac{\partial}{\partial z}\sum_{l,m} t_{lm} G_0(z;\mathbf{a}_l,\mathbf{a}_m). \tag{17}$$

In order to check the accuracy of the AVTA, we also performed a number of simulations on cubes with 13-16 oscillators on each side, and took a smoothed average of the density of states obtained for these systems.

The results of our calculations are shown in figure 1, in which we compare the densities of states in the periodic system (no defects) with that in the system with a concentration of 1.5% of these defects. We note first that in the periodic system the density of states $g(\omega)$ is fairly smooth, with the well-known van-Hove singularities, where there is a discontinuity in the gradient of $g(\omega)$, at $\omega = 2$ and $\omega = \sqrt{8}$. On the other hand, both the calculations and the simulations show a large peak in $g(\omega)$ around $\omega = 0.75$. This peak is not present for this density (9%) of randomly placed weak springs, as found by[9] and also in our own calculations and simulations for uncorrelated weak springs. It is very reminiscent of the peak in the density of low frequency vibrations found in glasses, where it is known as the Boson peak.[4] The difference in the heights of the maxima between the calculations and simulations are associated with the smoothing that has to be performed for the latter, and the areas under the peaks, which correspond to the total extra density of states in this region, are very similar. The slight difference in the positions of the peak may also be associated with this smoothing. However, it might just be a genuine effect arising from interactions between the defect clusters which are ignored in the AVTA but could occur in the simulated systems (where noise places a lower limit to the defect concentrations that can be studied). Incidentally, in the calculated density of states, there are slight problems at the frequencies of the Van-Hove singularities, as can be seen in figure 1, because of our use of equation (17), since the derivative of $G_0(z)$ is discontinuous at these points.

The main conclusions from this paper are that the presence of defect clusters involving correlated disorder extending over several sites can have an appreciable effect on the density of states. The average trace approximation (AVTA) presented in this paper provides a simple (at least in principle) and accurate

method of calculating the density of states in such systems for low concentrations of such clusters.

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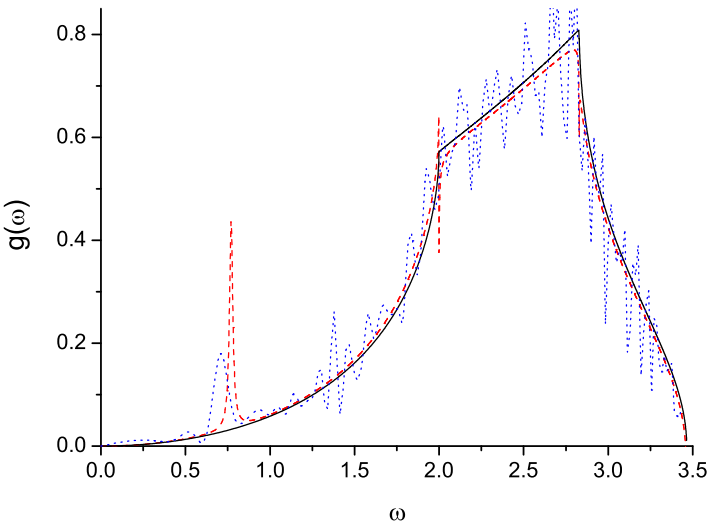
Caption for figure.

Fig.1 (Color on line) The density of states $g(\omega)$ as a function of the frequency ω for a system containing a concentration 1.5% of defects with six weak springs all having $K_1/K_0 = 0.1$. The continuous line shows $g(\omega)$ for the system without defects, the dashed line the density calculated using equation (17) and the dotted line that obtained from the simulations.


0.8
0.6
0.4
0.2
0.0
g(ω)
0.0
0.5
1.0
1.5
2.0
2.5
3.0
3.5
ω